

KBU Plastic-Encapsulate Bridge Rectifier

General Purpose Bridge Rectifier

Features

- I_O 10A
- V_{RRM} 50V-1000V
- High surge current capability
- Glass passivated chip

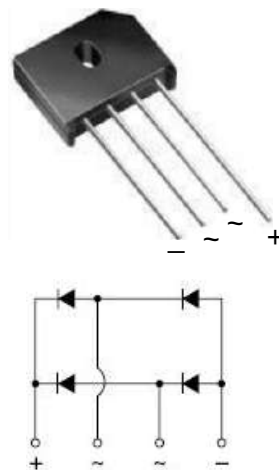
Applications

- General purpose 1 phase Bridge rectifier applications

Marking

- KBU10XX
- XX : From 005 To 10

KBU



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Conditions	KBU10						
				005	01	02	04	06	08	10
Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	200	400	600	800	1000
Average Rectified Output Current	I_O	A	60Hz sine wave, R-load $T_c = 100^\circ\text{C}$	10.0						
Surge(Non-repetitive) Forward Current	I_{FSM}	A	60Hz half-sine wave, 1 cycle, $T_j = 25^\circ\text{C}$	300						
Current Squared Time	I^2t	A^2S	$1\text{ms} \leq t < 8.3\text{ms}$ $T_j = 25^\circ\text{C}$, Rating of per diode	127.1						
Storage Temperature	T_{stg}	$^\circ\text{C}$		-55 ~ +150						
Junction Temperature	T_j	$^\circ\text{C}$		-55 ~ +150						

Electrical Characteristics ($T_a = 25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	Max
Peak Forward Voltage	V_{FM}	V	$I_{FM} = 10\text{A}$, Pulse measurement, Rating of per diode	1.0
Peak Reverse Current	I_{RRM}	μA	$V_{RM} = V_{RRM}$, Pulse measurement, Rating of per diode	5
Thermal Resistance	$R_{\theta J-A}$	$^\circ\text{C/W}$	Between junction and ambient	9
	$R_{\theta J-C}$		Between junction and case	5

Typical Characteristics

FIG.1-MAXIMUM FORWARD SURGE CURRENT

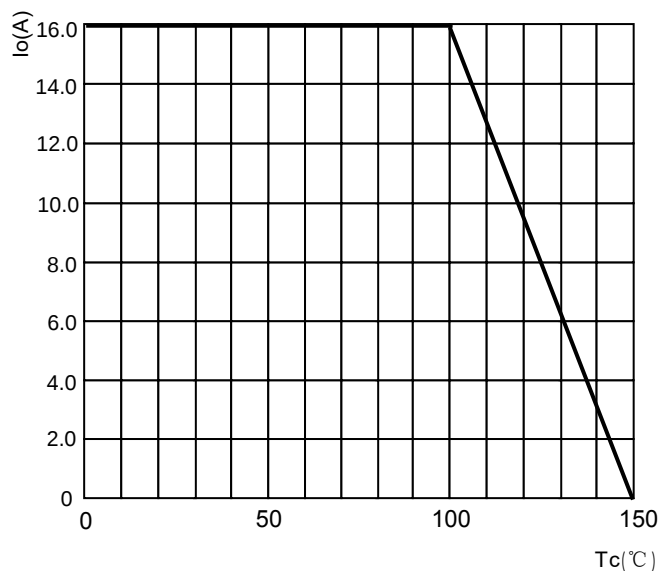


FIG.2-TYPICAL FORWARD CHARACTERISTICS

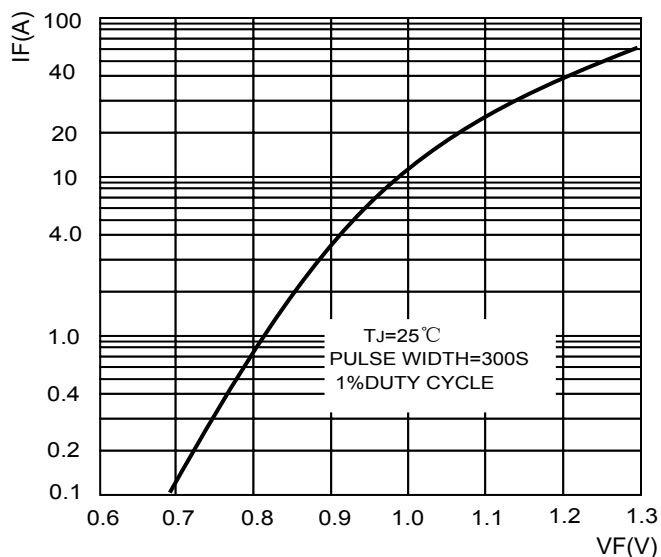


FIG.3-MAXIMUM NON-REPETITIVE SURGE CURRENT

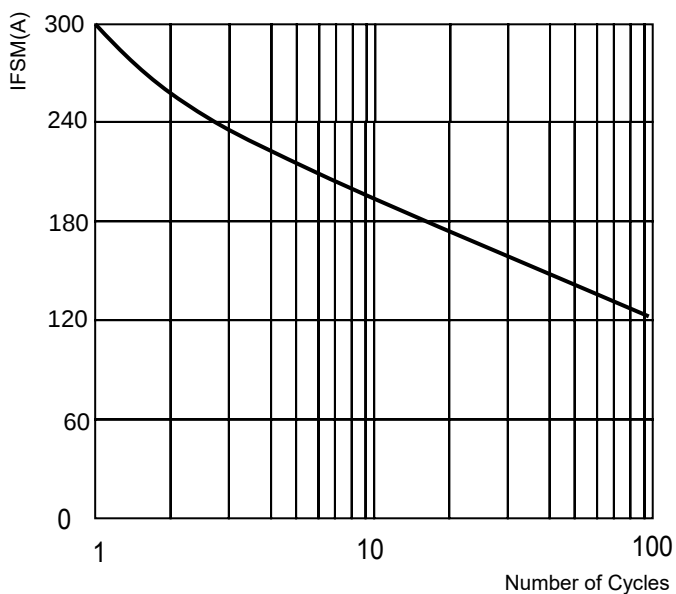


FIG.4-TYPICAL REVERSE CHARACTERISTICS

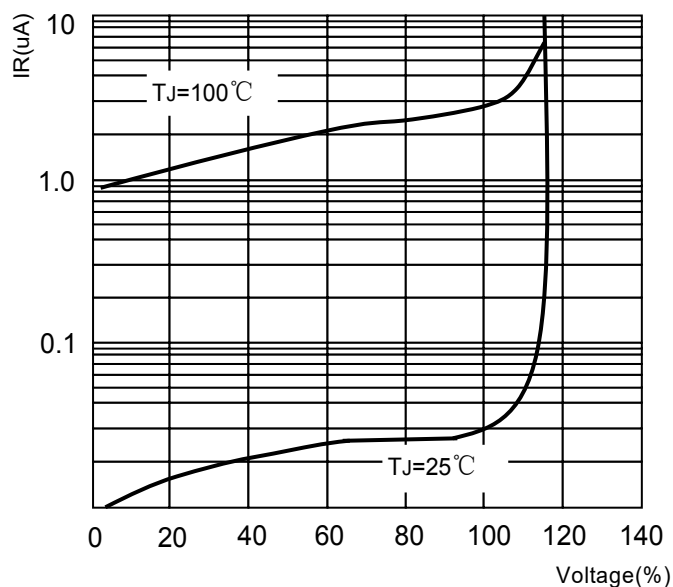
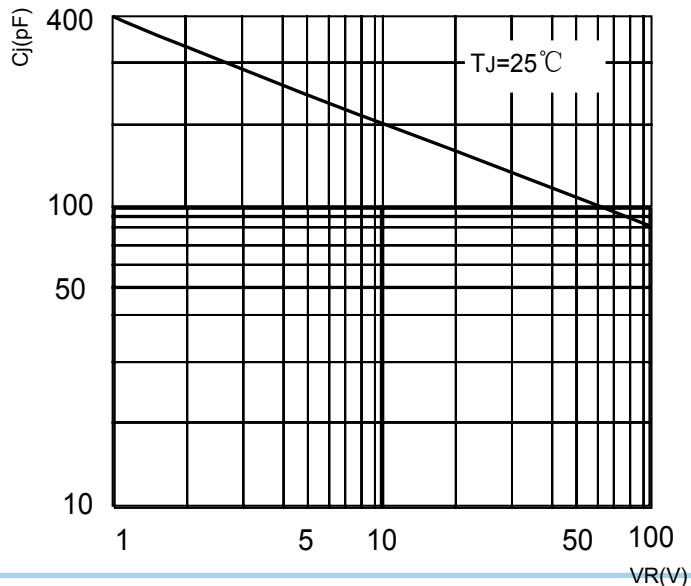
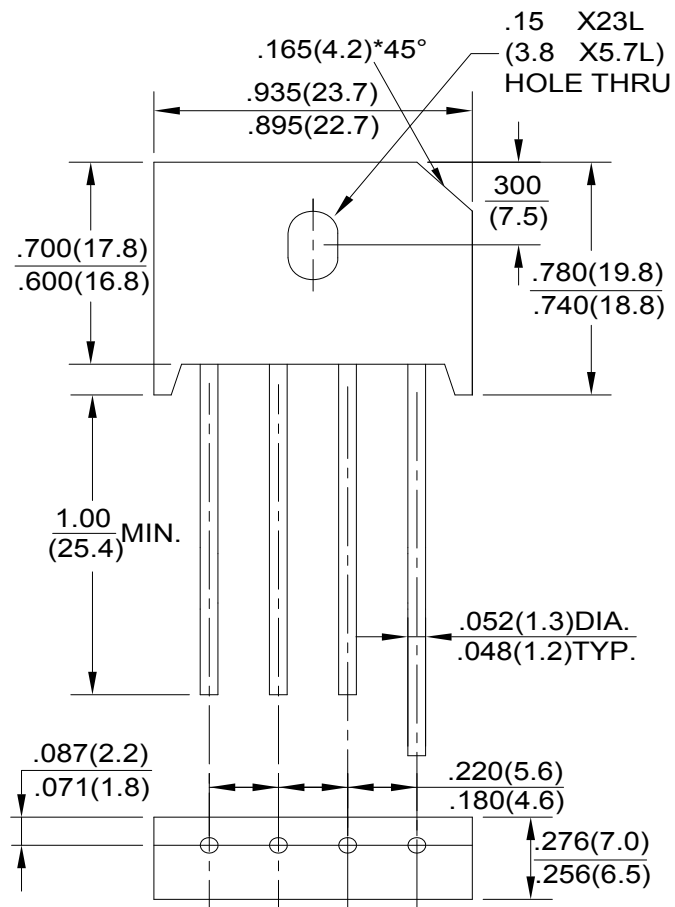


FIG.5-TYPICAL REVERSE CHARACTERISTICS



KBU Package Outline Dimensions



Dimensions in inches and (millimeters)